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October 1996 Revised June 2005

#### 74VCX16245

# **Low Voltage 16-Bit Bidirectional Transceiver** with 3.6V Tolerant Inputs and Outputs

#### **General Description**

The VCX16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation. The  $T/\overline{R}$  inputs determine the direction of data flow through the device. The  $\overline{OE}$  inputs disable both the A and B ports by placing them in a high impedance state.

The 74VCX16245 is designed for low voltage (1.2V to 3.6V)  $V_{CC}$  applications with I/O compatibility up to 3.6V.

The 74VCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

#### **Features**

- 1.2V to 3.6V V<sub>CC</sub> supply opera
- 3.6V tolerant inputs and couts
- l ten

2.5 ns max for 3. \to 3.6\

- Power-off higi pea e inpl and outpus
- Supp 'a ins 'on/v. .wal (Nc(e))
- (ic D ? (ic.
  - nA 3.0V V<sub>CC</sub>
- Uses prietary noise EM reduction circuit.y
- Latchup performal no exceeds 300 . 1A
- 3D performance

Human body model > 20001/

Machino mode! > 200V

ো ১৯৯০ packaged in plastic Fine-Fitch Ball Grid Array (FBGA)

**Note 1:** To ensure the high-imp dance state during power up or power down  $\overline{OE}$  should be tie i to  $V_{CC}$  through a pull-up resistor; the minimum  $v_i = 0^4$  the resistor is  $v_i = v_i$  mined by the current-sourcing capability of the diver.

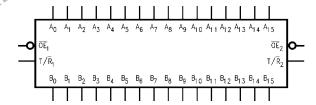
#### O. 'ering C de:

	dei	mber	Package Number   Package Description
	74 X1	6∠45G	CGA54A I5 -Ball Fin -Pi ch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
k	(N 32)	(Note 3)	
	. 4VCX1	32 45M TU	MTL 49 4o-L ad Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
	(Note 3		07, 12,

Note 2: Ordering code "G" In dicates Trays

N Y. 3: Devices also available in Take. Ind Reel. Specify by appending the suffix letter "X" to the ordering code.

#### Logic Symbol

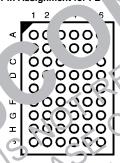


#### **Connection Diagrams**

#### Pin Assignment of TSSOP

		_	
⊺/R̄₁ —	1	48	— <del>o</del> e₁
В <sub>0</sub> —	2	47	— A <sub>0</sub>
В <sub>1</sub> —	3	46	— A <sub>1</sub>
GND —	4	45	— GNE
В <sub>2</sub> —	5	44	— A <sub>2</sub>
В <sub>3</sub> —	6	43	— A <sub>3</sub>
v <sub>cc</sub> —	7	42	— v <sub>cc</sub>
В4 —	8	41	— A₄
В <sub>5</sub> —	9	40	— A <sub>5</sub>
GND —	10	39	— GNE
В <sub>6</sub> —	11	38	— A <sub>6</sub>
В <sub>7</sub> —	12	37	— A <sub>7</sub>
В <sub>в</sub> —	13	36	— A <sub>8</sub>
В <sub>9</sub> —	14	35	— Ag
GND —	15	34	— GND
В <sub>10</sub> —	16	33	- A <sub>10</sub>
В <sub>1 1</sub> —	17	32	— A <sub>1 1</sub>
v <sub>cc</sub> —	18	31	— v <sub>cc</sub>
В <sub>12</sub> —	19	30	— A <sub>12</sub>
В <sub>13</sub> —	20	29	— A <sub>13</sub>
GND —	21	28	— GNE
В <sub>14</sub> —	22	27	— A <sub>14</sub>
В <sub>15</sub> —	23	26	— A <sub>15</sub>
⊺/R <sub>2</sub> —	24	25	— ŌE <sub>2</sub>

#### Pin Assignment for FB



#### **Pin Descriptions**

Pin Names	Description
<del>OE</del> <sub>n</sub>	Output Enable Input (Active LOW)
T/R <sub>n</sub>	Transmit/Receive Input
A <sub>0</sub> -A <sub>15</sub>	Side A Inputs or 3-STATE Outputs
B <sub>0</sub> -B <sub>15</sub>	Side B Inputs or 3-STATE Outputs
NC	No Connect

#### **FBGA Pin Assignments**

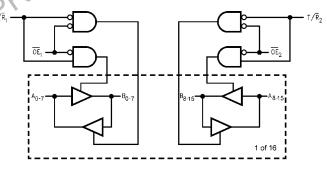
		1	2	3	4	5	
	Α	B <sub>0</sub>	NC	- 1	OF		A <sub>0</sub>
	В	B <sub>2</sub>	В		١٧C	A,	A <sub>2</sub>
	С	B <sub>4</sub>	B <sub>3</sub>	V <sub>CC</sub>	Vo	A <sub>3</sub>	.A <sub>2</sub>
	D	B <sub>6</sub>	B <sub>5</sub>	ID	,vD	1/5	A <sub>6</sub>
	E		کر	7 D	GND	177	A <sub>8</sub>
		В, 🤚	F .	NDت	GND	A <sub>9</sub>	A <sub>10</sub>
N			B <sub>11</sub>	V <sub>(C</sub>	/cc	A <sub>1</sub>	A <sub>12</sub>
۱	H	B <sub>14</sub>	B <sub>13</sub>	NC	NC	41.	A <sub>1/2</sub>
		B <sub>15</sub>	NC	1/R <sub>2</sub>	CE.	NC	F15

ŌĒ <sub>1</sub>	T/R	Outputs
1		Ru: L <sub>0</sub> -B <sub>7</sub> Data to Bus A <sub>0</sub> -A <sub>7</sub>
	Н	Eus A <sub>0</sub> -A <sub>7</sub> Data to Bus B <sub>0</sub> -B <sub>7</sub>
UH		HIGH Z State on A <sub>0</sub> -A <sub>7</sub> , B <sub>0</sub> -B <sub>7</sub>

7	1		
	Inp	uts	Outrots
4	ŌE <sub>2</sub>	T/R <sub>2</sub>	Outputs
Ì	L	L	Bus B <sub>8</sub> –B <sub>15</sub> Data to Bus A <sub>8</sub> –A <sub>15</sub>
	L	Н	Bus A <sub>8</sub> -A <sub>15</sub> Data to Bus B <sub>8</sub> -B <sub>15</sub>
	Н	X	HIGH Z State on A <sub>8</sub> -A <sub>15</sub> , B <sub>8</sub> -B <sub>15</sub>

- H = HIGH Voltage Level
- $\label{eq:Laplace} \begin{array}{l} L = LOW \ Voltage \ Level \\ X = Immaterial \ (HIGH \ or \ LOW, \ inputs \ and \ I/O's \ may \ not \ float) \\ Z = High \ Impedance \end{array}$

# Logic Diagram



#### **Absolute Maximum Ratings**(Note 4)

Supply Voltage (V<sub>CC</sub>) -0.5V to +4.6V DC Input Voltage (V<sub>I</sub>) -0.5V to +4.6V

Output Voltage (V<sub>O</sub>)

Outputs 3-STATE -0.5V to +4.6VOutputs Active (Note 5) -0.5 to  $V_{CC} + 0.5V$ DC Input Diode Current ( $I_{IK}$ )  $V_I < 0V$ -50 mA

DC Output Diode Current (I<sub>OK</sub>)

Supply Pin ( $I_{CC}$  or Ground)

 $V_{O} < 0V$ -50 mA  $V_{O} > V_{CC}$ +50 mA DC Output Source/Sink Current

 $(I_{OH}/I_{OL})$ 

 $\pm 50 \text{ mA}$ DC V<sub>CC</sub> or Ground Current per ±100 mA

-65°C to +150°C Storage Temperature Range (T<sub>STG</sub>)

#### **Recommended Operating** Conditions (Note 6)

Power Supply

1.2V to 3.6V Operating -0.3V to 3.6V Input Voltage

Output Voltage (V<sub>O</sub>)

Output in Active States 0V to V<sub>CC</sub> Output in 3-STATE 0.0V to 3.6V

Output Current in I<sub>OH</sub>/I<sub>OL</sub>

 $V_{CC} = 3.0V \text{ to } 3.6V$  $V_{CC} = 2.3V \text{ to } 2.7V$ ±18

 $V_{CC} = 1.65V \text{ to } 2.3V$ ±6 r  $V_{CC} = 1.4V \text{ to } 1.6V$ 'nΑ ±100 μΑ  $V_{CC} = 1.2V$ 

Free Air Operating \* mperatu **∪°C to** + 95°C

Minimum Inpu' dge te ( $\Delta t/\Delta$ 

10 ns/V  $V_{IN} = 0.8V$  to . V,  $V_{C} = 3.0$ 

Note 4: Ti.

"A Note 5: Ti.

"A note 5: Ti.

"A note 5: Ti.

"A note 6: Ti.

"

• 5: IO Absolute Maximum Rating must be ab ervad.

No. : Floating or unuser pin (inputs or I/O \\ r rust be hold H \c\H or LOW.

#### **DC Electrical Charact**

Symbol	Paramete.	Con àltims	(V)	Min	Max	Units
V <sub>IH</sub>	HIGH Leve put Voltage	ECYPO E	2.7 · 3.6 2.2 · 2.7 4.65 · 2.3	2.0 1.6 0.65 x V <sub>CC</sub>		٧
		COPILE	1.4 - 1.6 1.2	0.65 x V <sub>CC</sub> 0.65 x V <sub>CC</sub>		
V <sub>IL</sub>	I Input Vc tage	CATIO	2.7 - 3.6 2.3 - 2.7 1.65 - 2.3		0.8 0.7 0.35 x V <sub>CC</sub>	V
	CELEAS	$M_{II}$	1.4 - 1.6		0.35 x V <sub>CC</sub> 0.05 x V <sub>CC</sub>	v
V <sub>OH</sub>	HiGH Leve! Output Voltage	I <sub>OH</sub> = -100 µA I <sub>OH</sub> = -12 mA I <sub>OH</sub> = -18 mA I <sub>OH</sub> = -24 mA	2.7 - 3.6 2.7 3.0 3.0	V <sub>CC</sub> - 0.2 2.2 2.4 2.2		
	RE.	I <sub>OH</sub> = -100 µA I <sub>OH</sub> = -6 mA I <sub>OH</sub> = -12 mA I <sub>OH</sub> = -18 mA	2.3 - 2.7 2.3 2.3 2.3	V <sub>CC</sub> - 0.2 2.0 1.8 1.7		٧
		I <sub>OH</sub> = -100 μA I <sub>OH</sub> = -6 mA I <sub>OH</sub> = -100 μA	1.65 - 2.3 1.65 1.4 - 1.6	V <sub>CC</sub> - 0.2 1.25 V <sub>CC</sub> - 0.2		
		$I_{OH} = -100 \mu\text{A}$ $I_{OH} = -2 \text{mA}$ $I_{OH} = -100 \mu\text{A}$	1.4	1.05 V <sub>CC</sub> - 0.2		

#### DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.7 - 3.6		0.2	
		I <sub>OL</sub> = 12 mA	2.7		0.4	
		I <sub>OL</sub> = 18 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
		I <sub>OL</sub> = 100 μA	2.3 - 2.7		0.2	
		I <sub>OL</sub> = 12 mA	2.3		0.4	V
		I <sub>OL</sub> = 18 mA	2.3		.0	v
		I <sub>OL</sub> = 100 μA	1.65 - 2.3		0.2	
		I <sub>OL</sub> = 6 mA	1.65		3	
		$I_{OL} = 100 \mu A$	1.4 - 1.6		L	
		$I_{OL} = 2 \text{ mA}$	1.		0.35	( )
		$I_{OL} = 100 \mu A$	1.2		0.1 - ىر	$\Delta L \simeq$
l <sub>l</sub>	Input Leakage Current	$0V \le V_I \le 3.6V$	1.2 - 3.6		±5.0	μА
loz	3-STATE Output Leakage	$0V \le V_O \le 3.6V$	3.6		111	μА
		$V_I = V_{IH}$ or $V_{IL}$	0.0			ļu i
l <sub>OFF</sub>	Power Off Leakage Current	$0V \leq (V_I, V_O) \leq 3.6V$	0		10	μА
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or G <sup>N</sup>	.2 - 3.6		20	пД
		V <sub>CC</sub> ≤ (V / ≤ 3.6V \ 'e 7)	1.2 - 3.6		±. 0	
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	VIH = CC - V	2.7 - 3 6	G	/50	μΔ

Note 7: Outputs disabled or 3-STATE only.

#### AC Electrical Character te 8

Symbol	Param	Conditions	VC:	T <sub>A</sub> = -40 (	C to +C5°C	Units	Figure
Symbol	raiaii, i	Conducts	(V)	Mi'n	Max	Units	Number
t <sub>PHL</sub>	Propagatic Calay	$C_L = 30 \text{ pF, } R_L = 500\Omega$	3.3 ± 0.3	0.8	2.5		
t <sub>PLH</sub>		CO. C.	2.5 _ 0.2	1.0	3.0		Figures 1, 2
			. 8 ± 0.15	1.0	6.0	ns	-,-
		15 pF, R <sub>L</sub> = 2k. 2	1 5 ± 0.1	1.0	12.0		Figures
	7 / /	1 1 1	1.2	1.5	30		5, 6
†PZL	Ju. Enable Time	C <sub>L</sub> = 30 <sub>1</sub> F, R <sub>L</sub> = 5000	$3.3 \pm 0.3$	0.8	3.8		Figures
Ч			$2.5\pm0.2$	1.0	4.9		Figures 1, 3, 4
			$1.8\pm0.15$	1.5	9.3	ns	
	15 . 67	$C_L - 15 p^{-}, \kappa_L = 2k\Omega$	$1.5 \pm 0.1$	1.0	18.6		Figures
			1.2	1.5	46.5		5, 7, 8
t <sub>PLZ</sub>	ານປ <sub>ົ</sub> ບut Disable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	0.8	3.7		Figures
t <sub>PH Z</sub>	0///0/	ĺ	$2.5\pm0.2$	1.0	4.2		Figures 1, 3, 4
$\mathcal{N}$			$1.8\pm0.15$	1.5	7.6	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	$1.5 \pm 0.1$	1.0	15.2		Figures
			1.2	1.5	38		5, 7, 8
toshl	Output 1: Output	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$		0.5		
toslh	Sk. w (riote 9)		$2.5 \pm 0.2$		0.5		
	*		$1.8 \pm 0.15$		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	$1.5 \pm 0.1$		1.5		
			1.2		1.5		
Note 9: For	C 50nE add approximately 300ne to th	AC maximum appoification					

Note 8: For  $C_L = 50 pF$ , add approximately 300ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

3.3

#### **Dynamic Switching Characteristics** T<sub>A</sub> = +25°C ٧cc Symbol Conditions Units Parameter Typical (V) V<sub>OLP</sub> Quiet Output Dynamic Peak VOL $C_L = 30$ pF, $V_{IH} = V_{CC}$ , $V_{IL} = 0V$ ٧ 2.5 0.6 3.3 8.0 Quiet Output Dynamic Valley VOL $C_L=30~pF,~V_{IH}=V_{CC},~V_{IL}=0V$ 1.8 -0.25 $V_{OLV}$ 2.5 -0.6 -0.8 V<sub>OHV</sub> Quiet Output Dynamic Valley VOH $C_L = 30$ pF, $V_{IH} = V_{CC}$ , $V_{IL} = 0V$ 25

#### Capacitance

	Capa	citance		E.
	Symbol	Parameter	Conditions = +25° Units	) .
	C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 1.8V, 2.5V, or 3.3V, V <sub>I</sub> = 'or V <sub>V</sub> 6	
	C <sub>I/O</sub>	Output Capacitance	V <sub>I</sub> = 0V, or V <sub>CC</sub> , V <sub>CC</sub> = 1 8V, 2.5 3.3 7 pF	
	C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub> , F = 10 = V, 2.5 v or 3.3V 22 pF	
THIS	EV	CE IS NOTE CO	V <sub>CC</sub> = 1.8V, 2.5V, or 3.3V, V <sub>1</sub> =   Tor V <sub>1</sub>   6   PF     V <sub>1</sub> = 0V, or V <sub>CC</sub> , V <sub>CC</sub> = 1.8V, 2.5   3.3V   7   PF     V <sub>1</sub> = 0V or V <sub>CC</sub> , F = 10   9   9   9   9   9   9     V <sub>1</sub> = 0V or V <sub>CC</sub> , F = 10   9   9   9   9   9   9   9   9   9	

### AC Loading and Waveforms (V $_{\text{CC}}$ 3.3V $\pm$ 0.3V to 1.8V $\pm$ 0.15V)

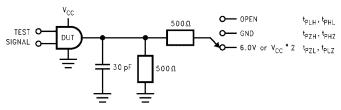
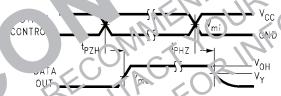


FIGURE 1. AC Test Circuit

TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
$t_{PZL}$ , $t_{PLZ}$	6V at $V_{CC} = 3.3 \pm 0.3V$ ;
	$V_{CC}$ x 2 at $V_{CC}$ = 2.5 ± 0.2V; 1.8V  \text{.15}\
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND



FIGURE 2. ' 'eforn 'r Invert, and Non inver ing Function'



. 3. 3-S\*ATE Output Hig., 51 able and Disax le Times for Low Voltage Logic

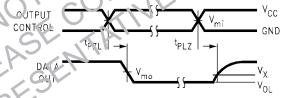
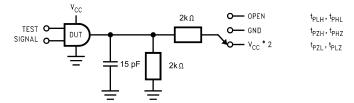


FIGURE 4. 3-3 TATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V <sub>cc</sub>				
- Cymbei	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V		
V <sub>mi</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2		
V <sub>mo</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2		
V <sub>X</sub>	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V	V <sub>OL</sub> + 0.15V		
V <sub>Y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V	V <sub>OH</sub> – 0.15V		

#### AC Loading and Waveforms (V $_{CC}$ 1.5V $\pm$ 0.1V to 1.2V)



TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
$t_{PZL}$ , $t_{PLZ}$	$V_{CC}$ x 2 at $V_{CC}$ = 1.5 ± 0.1V

FIGURE 5. AC Test Circuit

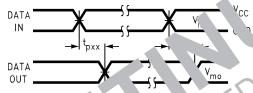
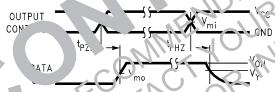
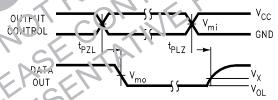


FIGURE 6. Waveform to Inverting and Non-Inverting Functions



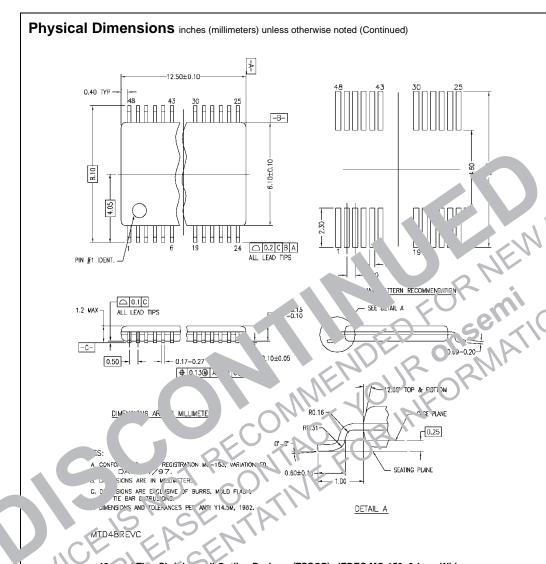
FI RE 7. 3 TATE Output high Enable and Disable Times for Low Voltage Logic



FICURE 8. 3-S1.172 Curput Low Enable and Disable Times for Low Voltage Logic

Symbol	V <sub>CC</sub>
	1.5V ± 0.1V
V <sub>mi</sub>	V <sub>CC</sub> /2
$V_{mo}$	V <sub>CC</sub> /2
V <sub>X</sub>	V <sub>OL</sub> + 0.1V
$V_{Y}$	V <sub>OH</sub> – 0.1V

## 74VCX16245 Physical Dimensions inches (millimeters) unless otherwise noted ○ 0.10 B В 5.5 8.0 Α 0.4 0.10 A (0.75) DED FORMEN DESIGNATION 00000 EFGHJ PIN ONE 8 ABCD Top 54X 0.5<sup>+0.05</sup> View 0.15M C 30.0 // 0.15 C 1.4MAX ─ ES: A HIS PAC GE CONFORMS TO JEDEC M 1-705 B. DIME HONS IN VIII LINETERS C. L. FERN RECUMMENDATION, NSMD (Non Suider Mask Defined) 35Min DIA PADS WITH A SOLDER MASK OPE: IN GOF. 45MM CONCENTRIC TO PADS L. DRAWING CONFORMS TO ASMEY 14.5M-19.44 BGA54ArevD ¼-Ball Fine-F tch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A



48 Cend Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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